

BSP297 E6327 Information


For Reference Only

Part Number [BSP297 E6327](#)
Manufacturer Infineon Technologies
Category Discrete Semiconductor Products
[Transistors - FETs, MOSFETs - Single](#)
Description MOSFET N-CH 200V 660MA SOT-223
Package TO-261-4, TO-261AA
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


[Request a Quote](#)
Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


BSP297 E6327 Specifications

Manufacturer Part Number	BSP297 E6327
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
Package	TO-261-4, TO-261AA
Series	SIPMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vds)	200V
Current - Continuous Drain (Id) @ 25°C	660mA (Ta)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	1.8V @ 400µA
Gate Charge (Qg) (Max) @ Vgs	16.1nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	357pF @ 25V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	1.8W (Ta)
Rds On (Max) @ Id, Vgs	1.8 Ohm @ 660mA, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	PG-SOT223-4
Package / Case	TO-261-4, TO-261AA

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BSP297 E6327 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

BSP297 E6327 Payment Methods



BSP297 E6327 Shipping Methods



If you have any question about BSP297 E6327, please do not hesitate to contact us!

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